The 6th International Workshop on Future Tau Charm Facilities

FTCF, 2024, Guangzhou

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Research progress on long lifetime MCP-PMT

Ping Chen

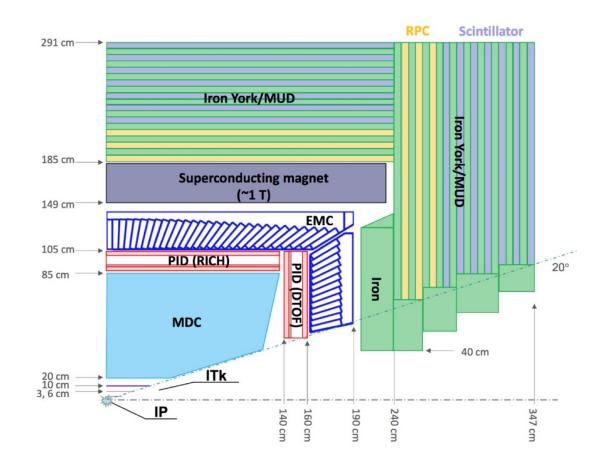
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20/11/2024

STCF PID (DTOF)



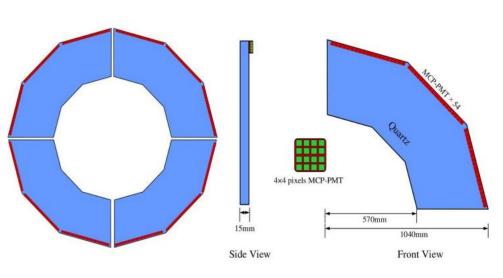


MCP-PMT requirements

- 4x4 anodes
- Gain > 1E6
- TTS < 100 ps

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- QE > 20%
- Lifetime > ten years (IAC > 10C/cm2)
- High rate capability



DTOF: DIRC-like TOF

MCP-PMTs by XIOPM



Φ25mm Fast/Gated Φ18mm Fast/Gated 20 inch MCP-PMT **MCP-PMT MCP-PMT** 中国科学院西安 中国科学院西安 :快响应MCP-PM 国科学院西安 国科学院西安 快响应MCP-PM 门控型MCP-P]控型MCP-H 25-M-231 18-1-230428 8-NA 2311

Φ50mm Large current MCP-PMT



Φ80mm Large current MCP-PMT



MCP-maPMT Long lifetime MCP-maPMT





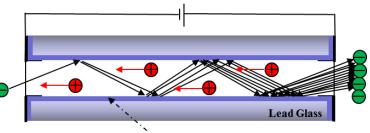


Microchannel plate

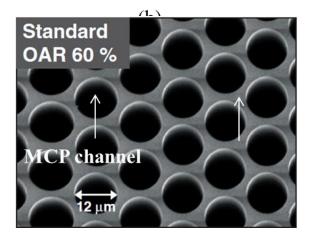


Conventional MCP

- Made of lead glass
- Collection efficiency ~60%
- Gain from lead glass
- Maximum SEE yield \sim 3

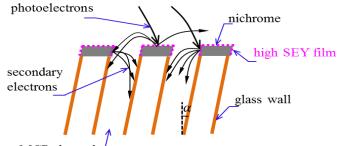


Lead Reduction Layer



□ ALD-MCP based on lead glass □ ALD-MCP based on borosilicate

- Coating Al2O3/MgO on the lead glass MCP input surface and channel
- Maximum SEE yield over 4
- Gain mainly from ALD-layer
- Collection efficiency improved to ~100%
- Improve CE of 20"MCP-PMT for JUNO
- Lifetime extended



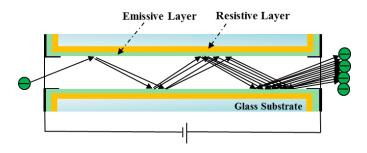
MCP channel

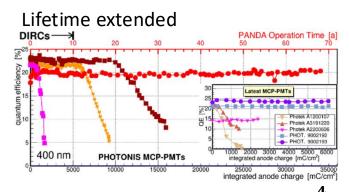
20 inch MCP-PMT for JUNO



glass

- Lead free
- ALD coating resistive layer and emissive layer
- Gain resulted from ALD-Layer
- Maximum SEE over 4
- Lifetime extended





A. Lehmann et al., GSI scientific report 2022D01:10.15120/GS1-2023-00462

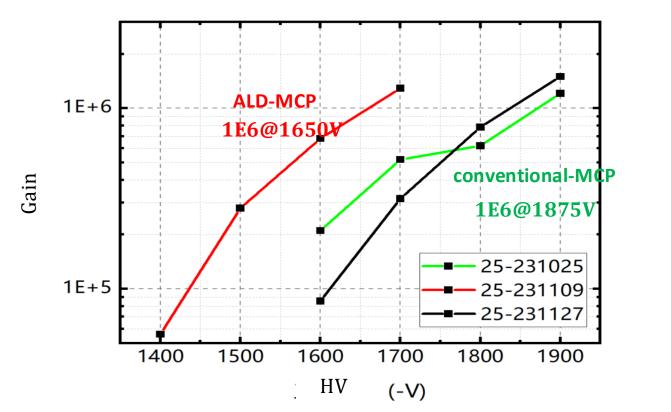
gain

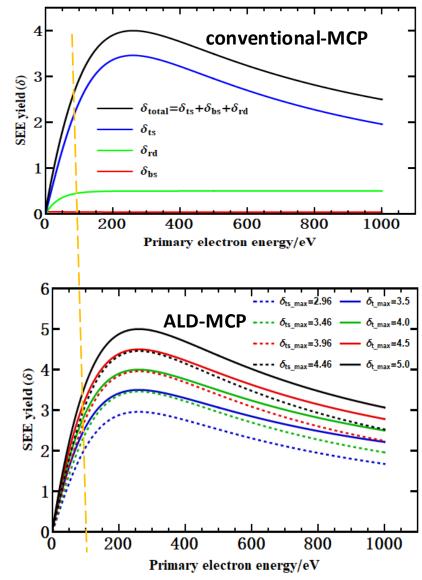


ALD-MCP

Higher gain at lower HV

• Higher SEE yield for ALD-MCP





lifetime

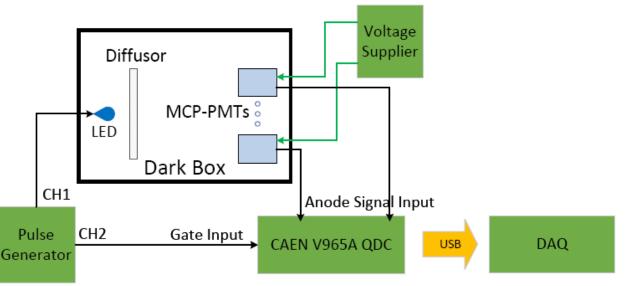


Factors affecting the lifetime of MCP-PMT?

- Single anode MCP-PMTs produced for lifetime study
 - 25 mm diameter
 - MCPs with and without ALD layer
 - ALD layer of 1 nm, 4.5 nm, 6nm thickness
 - MCP scrubbed amount of 0.43~0.75 uA·h/cm²
 - Worked at gain of 5e5~1e6
- Light source
 - LED driven by a pulse generator
 - 10 ns pulse width
 - 405 nm wavelength

Integrated anode charge : IAC = $\sum \overline{q} \cdot t \cdot f$





lifetime

Influence of ALD film thickness

Lifetime@6 nm > 4.5 nm > 1nm > none

Influence of scrubbing amount

Lifetime: @0.75 uA·h/cm² > 0.52 uA·h/cm² > 0.43 uA·h/cm²

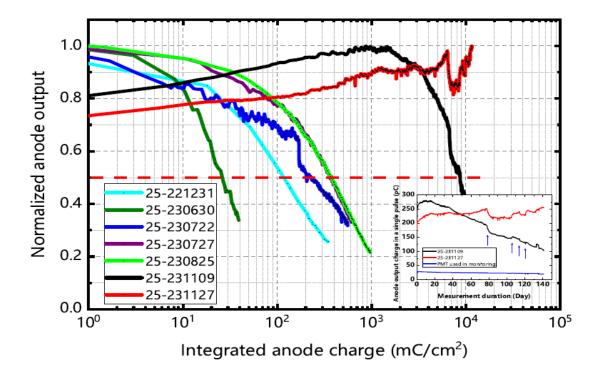


Table 2. IAC at 50% anode output degradation for the MCP-PMTs.

ID	Thickness of the ALD-layer (nm)	Electron scrubbing dosage $(\mu A \cdot h/cm^2)$	IAC at 50% degradation (mC/cm ²)
25-221231	1	0.43	117
25-230630	None	0.43	26
25 - 230722	1	0.52	230
25 - 230727	1	0.75	373
25 - 230825	1	0.75	373
25 - 231109	4.5	0.75	8800
25-231127	6	0.75	> 11,000

IAC over 11 C/cm2



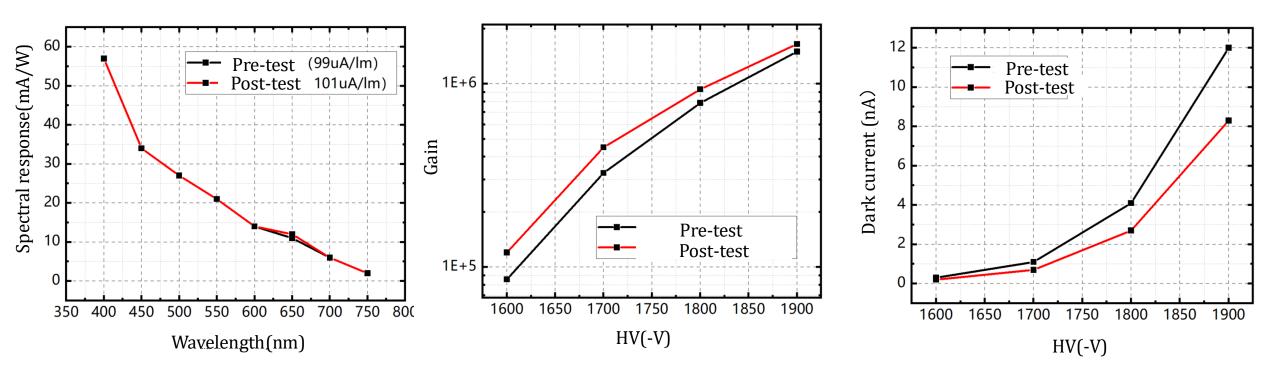
lifetime



Performances before and after lifetime tests

25-231127 with IAC over 11 C/cm2

none degradation on photocathode and MCP



Lifetime



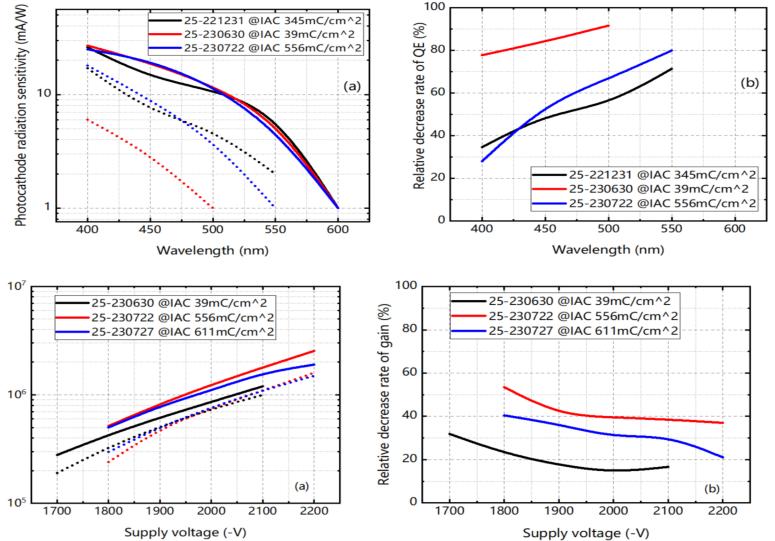
Performances before and after lifetime tests

Gain

QE decreases more at longer wavelengths

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Table 2. IAC at 50% anode output degradation for the MCP-PMTs.

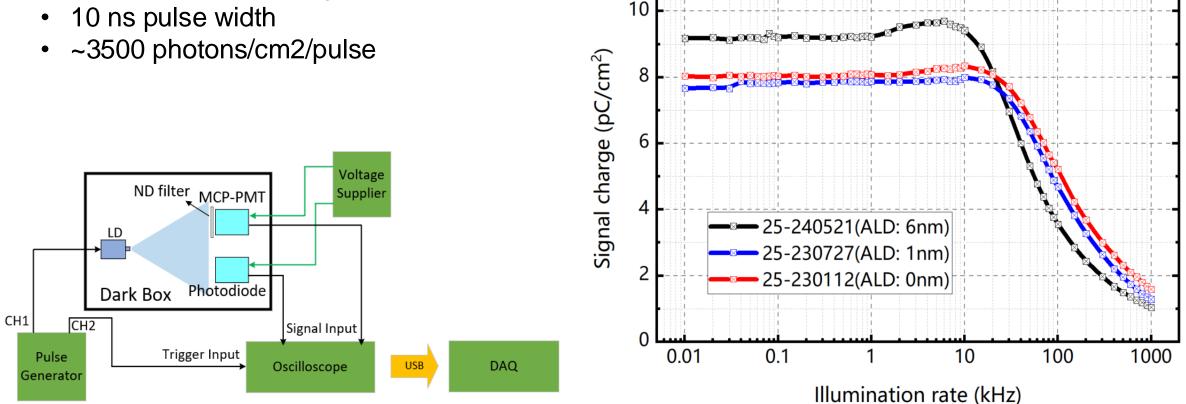


Rate capability



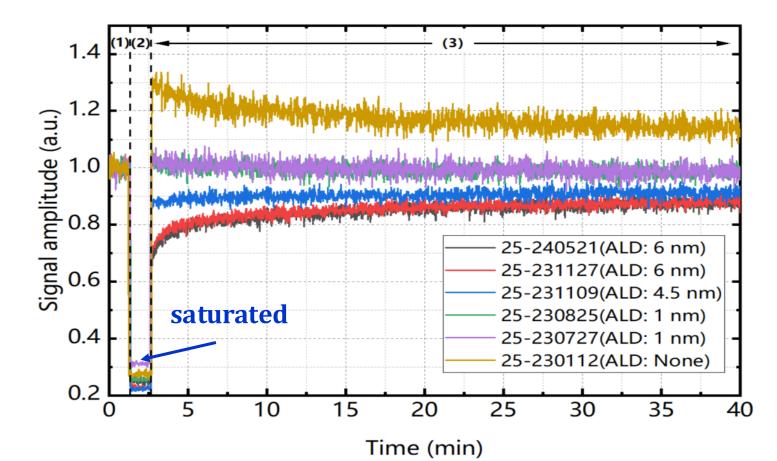
measurement setup

- Single-anode MCP-PMTs with 25 mm diameter ٠
- LD driven by a pulse generator ٠
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ALD film effect

- MCP-PMTs with different thickness of ALD film operated at 1E5 gain
- illuminated by LD at rates of 10 Hz \sim 500 kHz \sim 10 Hz for 84 seconds to be saturated



Longer recovery time for

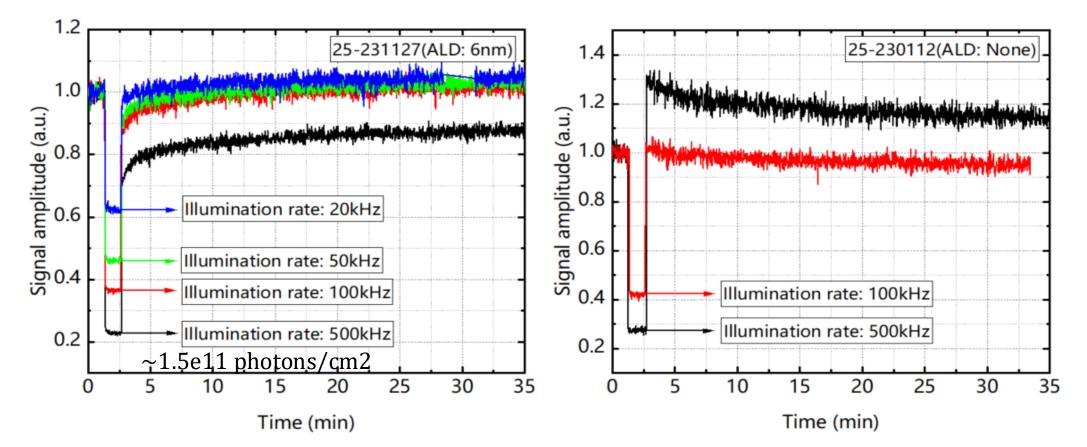
thicker ALD-layer MCP

• Super linearity for none-ALD MCP ?



Illumination rate effect

- The greater the degree of saturation, the slower the recovery
- Super linearity is worse at higher rate for none-ALD MCP





Super linearity for none-ALD MCP

- Single-anode MCP-PMT with 50 mm diameter
- PD for monitoring light source
- Super linearity is worse for stronger illumination

Light source 400ns, 0.4V

400ns,1.4V

400ns宽度较强光脉冲激励下输出波形

PD

200

Time(ns)

300

MCP-PM1

1.5

0.5

-100

0

100

Amplitude(V)

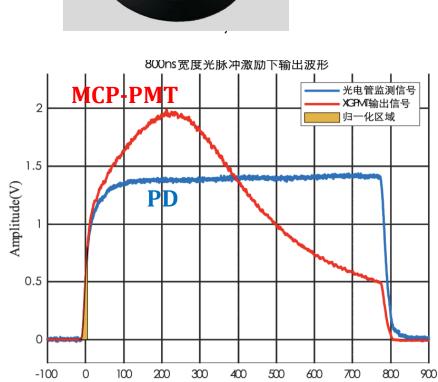
光电管监测信号

XGPMI输出信号

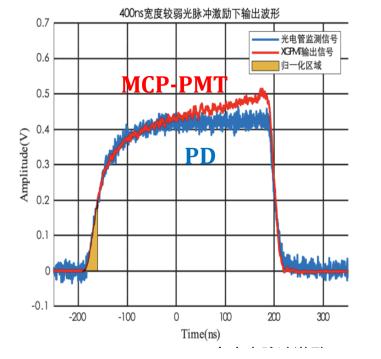
归一化区域

400

500



Time(ns)

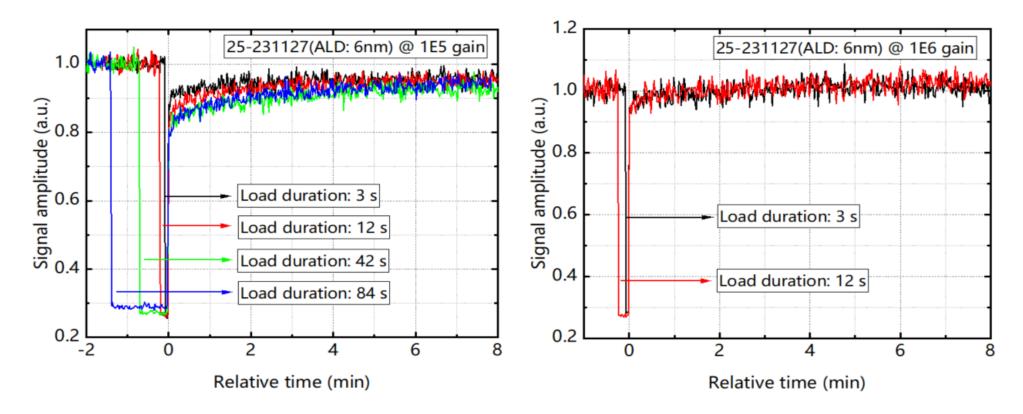






Saturation duration effect

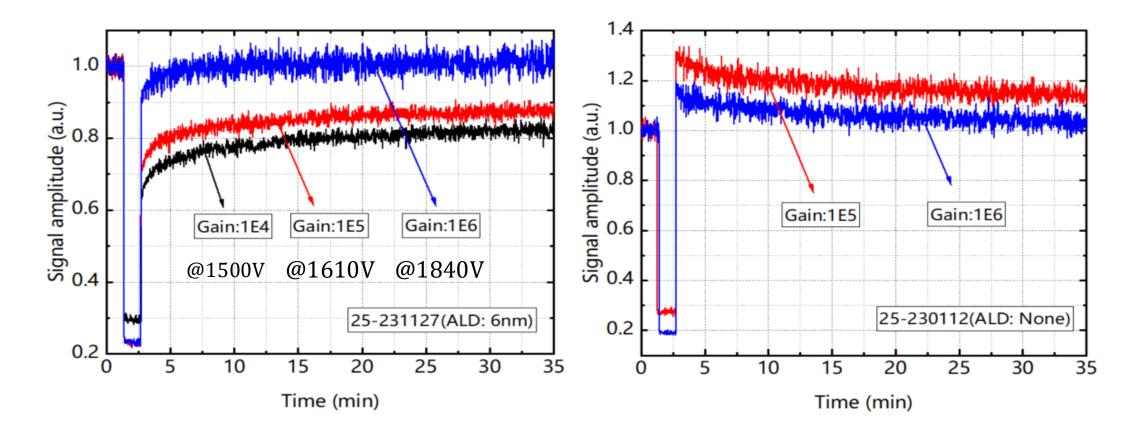
- The longer the saturation duration, the slower the recovery.
- When the saturation duration exceeds a certain value(e.g. 42s), the recovery behavior no longer changes.





Supply voltage effect

- Higher supply voltage is better for recovery for the ALD-MCP
- Super linearity is less for higher HV





Summary & outlook



- □ ALD film on lead glass MCP is efficient for improve the lifetime.
- □ Increasing scrubbing amount for MCP is also good for lifetime.
- □ Thicker ALD-MCP has longer recovery time.
- The ALD film should be optimized considering the gain, lifetime and rate capability.
- Super linearity is found in the non ALD-MCP, which needs to be studied further.
- Higher supply voltage seems better for gain recovery.
- The ALD-film and scrubbing amount for MCP will be optimized for improving lifetime further.
- □ The single photon rate capability will be evaluated.



Thank you for your attention !